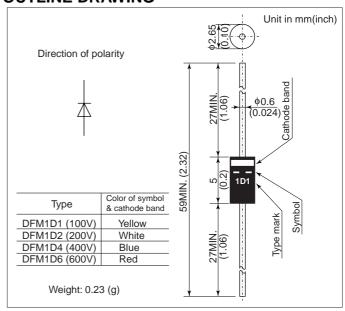
DFM1D

FEATURES

- For high speed switching.
- Diffused-junction. Resin encapsulated.

OUTLINE DRAWING



ABSOLUTE MAXIMUM RATINGS

/ D001011 11/7 Ullinoin 10 Ullinoi											
Items	Туре		DFM1D1	DFM1D2	DFM1D4	DFM1D6					
Repetitive Peak Reverse Voltage	V_{RRM}	V	100	200	400	600					
Average Forward Current	I _{F(AV)}	А	1.0 (Single-phase half sine wave 180° conduction TL = 57°C, Lead length = 6mm								
Surge(Non-Repetitive) Forward Current	I _{FSM}	Α	40(Without PIV, 10ms conduction, Tj = 40°C start)								
I ² t Limit Value	l ² t	A ² s	6.4(Time = 2 ~ 10ms, I = RMS value)								
Operating Junction Temperature	Tj	°C	-40 ~ + 150								
Storage Temperature	T _{sta}	°C	-40 ~ +150								

Notes (1) Lead mounting: Lead temperature 280°C max. to 3.2mm from body for 5sec. max..

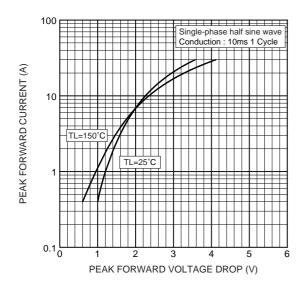
(2) Mechanical strength: Bending 90°×2 cycles or 180°×1 cycle, Tensile 2kg, Twist 90°×1 cycle.

CHARACTERISTICS(T₁=25°C)

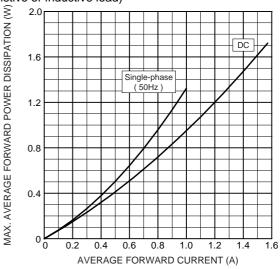
Items	Symbols	Units	Min.	Тур.	Max.	Test Conditions	
Peak Reverse Current	I _{RRM}	μΑ	_	_	20	DFM1D1,2	Rated V _{RRM}
					10	DFM1D4,6	
Peak Forward Voltage	V_{FM}	V	_	_	1.2	I _{FM} =1.0Ap, Single-phase half sine wave 1 cycle	
Reverse Recovery Time	trr	μs	_	_	0.2	I _F =0.5A, I _{rp} =1.0A, 25%recovery	
Steady State Thermal Impedance	$R_{th(j-a)}$ $R_{th(j-l)}$	°C/W	_	_	100 70	Lead length = 6 mm	

DFM1D

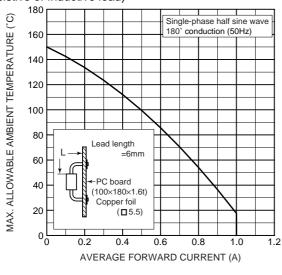
Forward characteristics



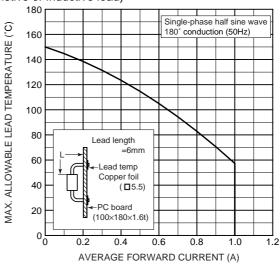
Max. average forward power dissipation (Resistive or inductive load)



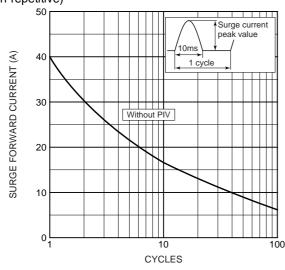
Max. allowable ambient temperature (Resistive or inductive load)



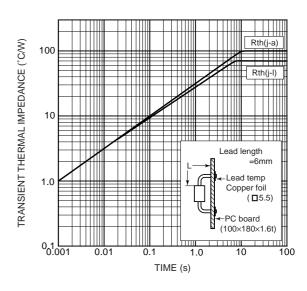
Max. allowable lead temperature (Resistive or inductive load)



Surge forward current characteristic (Non-repetitive)

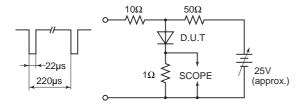


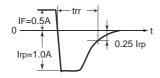
Transient thermal impedance



DFM1D

Reverse recovery time(trr) test circuit





HITACHI POWER SEMICONDUCTORS

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